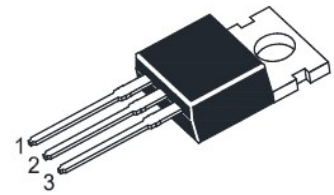


2SA1010-HAF

PNP Silicon Epitaxial Planar Power Transistor

Features

- Low collector saturation voltage
- Fast switching speed
- Halogen and Antimony Free(HAF), RoHS compliant



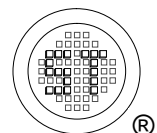
1.Base 2.Collector 3.Emitter
TO-220FB Plastic Package

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Collector Base Voltage	$-V_{CBO}$	100	V
Collector Emitter Voltage	$-V_{CEO}$	100	V
Emitter Base Voltage	$-V_{EBO}$	7	V
Collector Current	$-I_C$	7	A
Peak Collector Current	$-I_{CM}$	15	A
Base Current	$-I_B$	3.5	A
Total Power Dissipation	P_{tot}	$T_a = 25^\circ\text{C}$ 1.5 $T_c = 25^\circ\text{C}$ 41.7	W
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 150	$^\circ\text{C}$

Thermal Characteristics

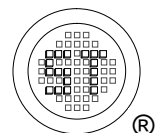
Parameter	Symbol	Max.	Unit
Thermal Resistance - Junction to Case	$R_{\theta JC}$	3	$^\circ\text{C}/\text{W}$
Thermal Resistance - Junction to Ambient	$R_{\theta JA}$	83.3	$^\circ\text{C}/\text{W}$



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Characteristics at $T_j = 25^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $-V_{CE} = 5\text{ V}$, $-I_C = 5\text{ A}$ at $-V_{CE} = 5\text{ V}$, $-I_C = 3\text{ A}$ Current Gain Group	M				
	L				
	K				
Collector Base Cutoff Current at $-V_{CB} = 100\text{ V}$	$-I_{CBO}$	-	-	10	μA
Emitter Base Cutoff Current at $-V_{EB} = 5\text{ V}$	$-I_{EBO}$	-	-	10	μA
Collector Emitter Saturation Voltage at $-I_C = 5\text{ A}$, $-I_B = 0.5\text{ A}$	$-V_{CE(sat)}$	-	-	0.6	V
Base Emitter Saturation Voltage at $-I_C = 5\text{ A}$, $-I_B = 0.5\text{ A}$	$-V_{BE(sat)}$	-	-	1.5	V
Turn-On Time at $-I_C = 5\text{ A}$, $I_{B1} = -I_{B2} = -0.5\text{ A}$, $-V_{CC} = 50\text{ V}$, $R_L = 10\ \Omega$	t_{on}	-	-	0.5	μs
Storage Time at $-I_C = 5\text{ A}$, $I_{B1} = -I_{B2} = -0.5\text{ A}$, $-V_{CC} = 50\text{ V}$, $R_L = 10\ \Omega$	t_{stg}	-	-	1.5	μs
Fall Time at $-I_C = 5\text{ A}$, $I_{B1} = -I_{B2} = -0.5\text{ A}$, $-V_{CC} = 50\text{ V}$, $R_L = 10\ \Omega$	t_f	-	-	0.5	μs
Collector Output Capacitance at $V_{CB} = 10\text{ V}$, $f = 1\text{ MHz}$	C_{ob}	-	-80	-	pF



Electrical Characteristics Curves

Fig. 1 Output Characteristics Curve

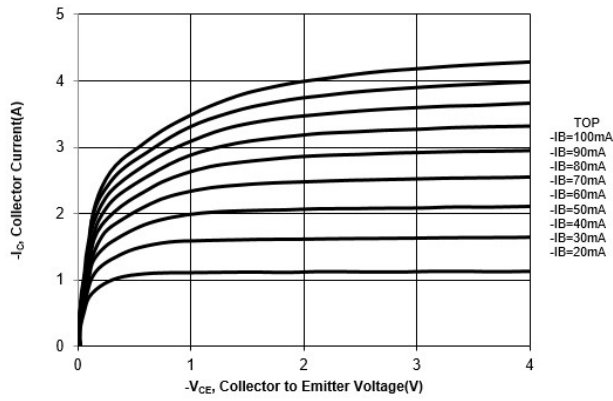


Fig. 2 Output Characteristics Curve

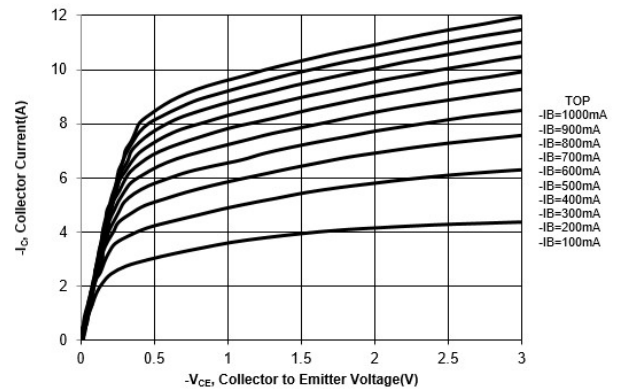


Fig. 3 Collector Current vs. V_{BE}

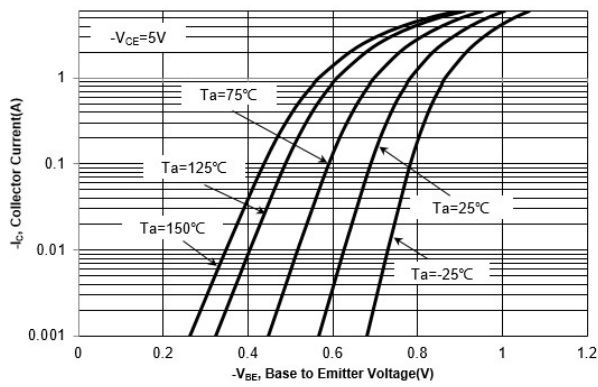
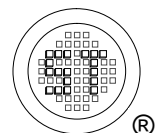
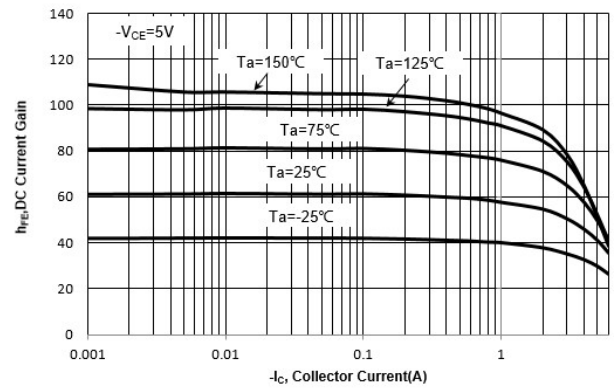


Fig. 4 h_{FE} vs. Collector Current



Electrical Characteristics Curves

Fig. 5 $V_{BE(sat)}$ vs. Collector Current

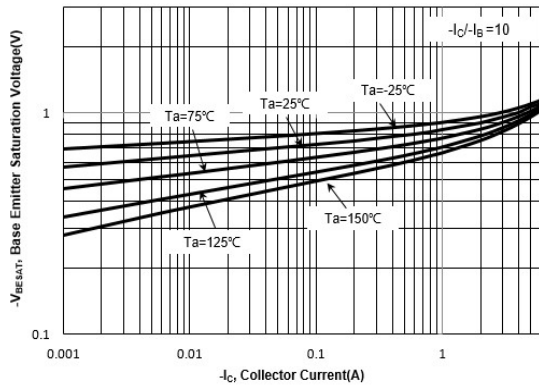


Fig. 6 $V_{CE(sat)}$ vs. Collector Current

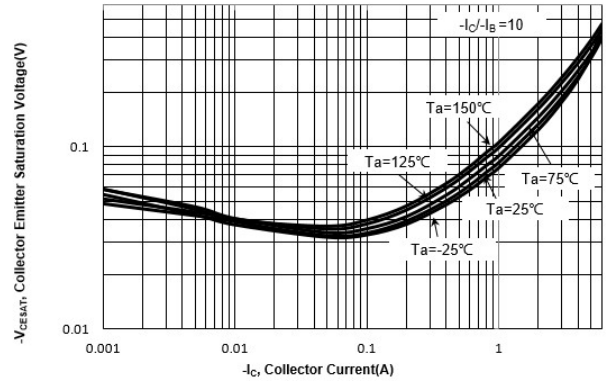


Fig. 7 Output Capacitance

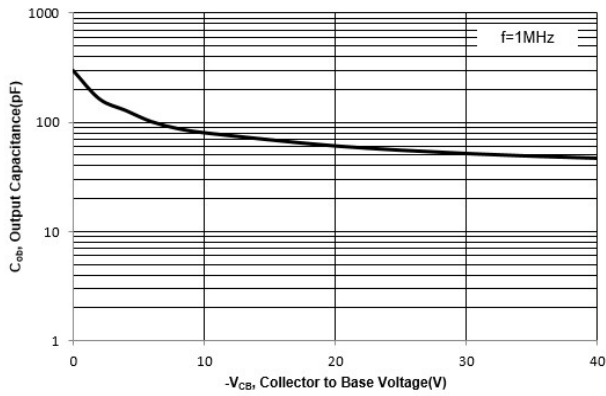
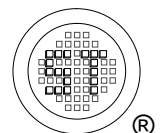
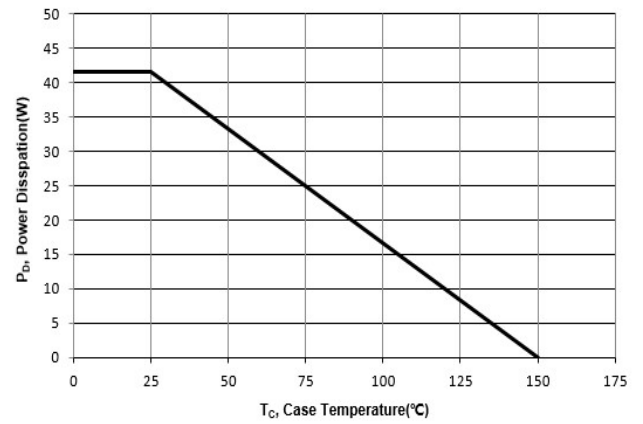


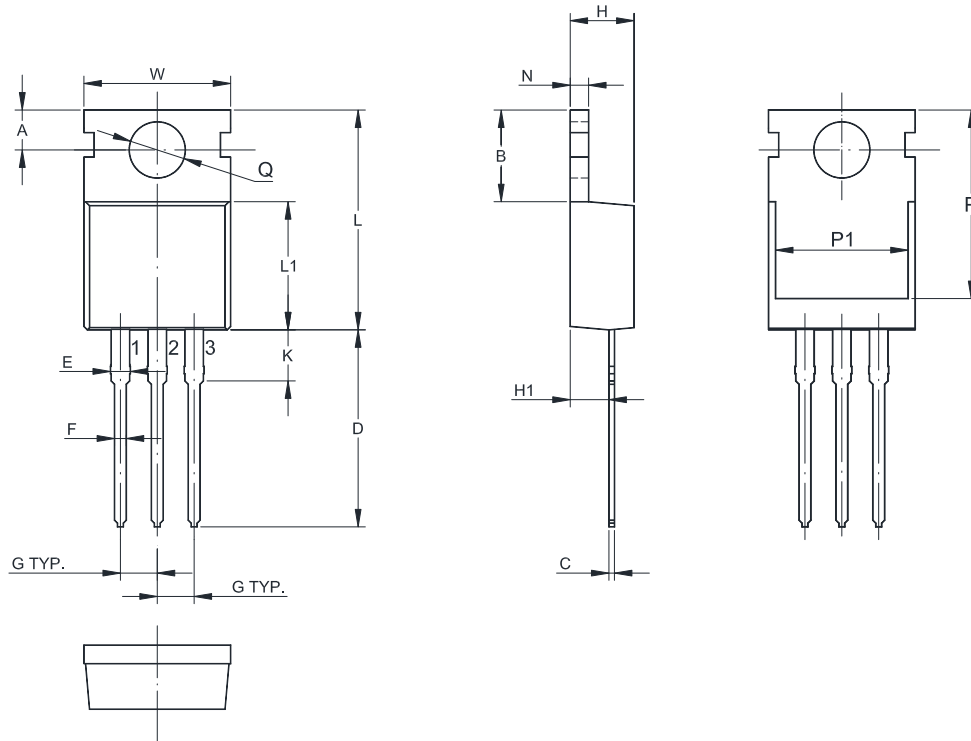
Fig. 8 Power Derating Curve



2SA1010-HAF

Package Outline Dimensions (Units: mm)

TO-220FB



UNIT	A	B	C	D	E	F	G	W	H	H1	K	L	L1	N
mm	2.9	6.8	0.7	15	1.5	0.9	2.54	10.2	4.7	2.5	3.1	16.8	9.4	1.4
	2.7	6.4	0.3	11	1.1	0.7	Typ.	9.8	4.3	2.2	2.7	14.8	9.0	1.2

UNIT	P	P1	Q
mm	13.3	8.2	3.7
	12.7	7.6	3.5

Marking information

" 2SA1010* " = Part No. (" * " = HFE grouping Code)

" ***** " = Date Code Marking

Font type: Arial

